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HUF75639G3, HUF75639P3, HUF75639S3S, HUF75639S3

Data Sheet

October 2013

N-Channel UltraFET Power MOSFET 100 V, 56 A, 25 mΩ

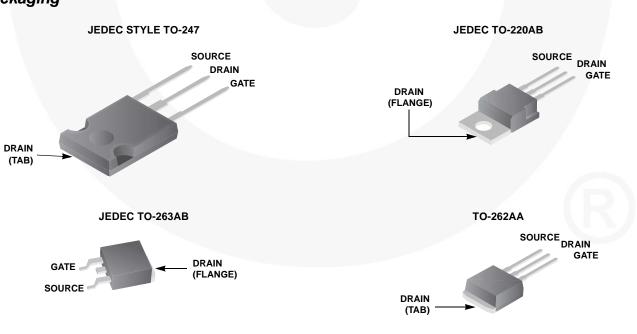
These N-Channel power MOSFETs are manufactured using the innovative UltraFET process. This advanced process technology achieves the lowest possible onresistance per silicon area, resulting in outstanding performance. This device is capable of withstanding high energy in the avalanche mode and the diode exhibits very low reverse recovery time and stored charge. It was designed for use in applications where power efficiency is important, such as switching regulators, switching converters, motor drivers, relay drivers, low-voltage bus switches, and power management in portable and batteryoperated products.

Formerly developmental type TA75639.

Ordering Information

PART NUMBER	PACKAGE	BRAND
HUF75639G3	TO-247	75639G
HUF75639P3	TO-220AB	75639P
HUF75639S3ST	TO-263AB	75639S
HUF75639S3	TO-262AA	75639S

Packaging



Product reliability information can be found at http://www.fairchildsemi.com/products/discrete/reliability/index.html For severe environments, see our Automotive HUFA series.

All Fairchild semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.

56A, 100VSimulation Models

Features

- Temperature Compensated PSPICE® and SABER™ Electrical Models
- Spice and Saber Thermal Impedance Models
- www.fairchildsemi.com
- Peak Current vs Pulse Width Curve
- UIS Rating Curve
- Related Literature
 - TB334, "Guidelines for Soldering Surface Mount Components to PC Boards"

Symbol

Absolute Maximum Ratings $T_C = 25^{\circ}C$, Unless Otherwise Specified

		UNITS
Drain to Source Voltage (Note 1)V _{DSS}	100	V
Drain to Gate Voltage ($R_{GS} = 20k\Omega$) (Note 1)	100	V
Gate to Source Voltage	±20	V
Drain Current		
Continuous (Figure 2)	56	А
Pulsed Drain Current	Figure 4	
Pulsed Avalanche Rating E _{AS}	Figures 6, 14, 15	
Power Dissipation P _D	200	W
Derate Above 25 ^o C	1.35	W/ ^o C
Operating and Storage Temperature	-55 to 175	°C
Maximum Temperature for Soldering		
Leads at 0.063in (1.6mm) from Case for 10s	300	°C
Package Body for 10s, See Techbrief 334	260	°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. $T_J = 25^{\circ}C$ to $150^{\circ}C$.

Electrical Specifications $T_{C} = 25^{\circ}C$, Unless Otherwise Specified

PARAMETER	SYMBOL	TEST	CONDITIONS	MIN	TYP	MAX	UNITS
OFF STATE SPECIFICATIONS					+		
Drain to Source Breakdown Voltage	BV _{DSS}	$I_{D} = 250 \mu A, V_{GS} =$	0V (Figure 11)	100	-	-	V
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 95V, V _{GS} =	0V	-	-	1	μΑ
		V _{DS} = 90V, V _{GS} =	0V, T _C = 150 ^o C	-	-	250	μΑ
Gate to Source Leakage Current	I _{GSS}	$V_{GS} = \pm 20V$		-	-	±100	nA
ON STATE SPECIFICATIONS					1		
Gate to Source Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D = 2$	50μA (Figure 10)	2	-	4	V
Drain to Source On Resistance	^r DS(ON)	I _D = 56A, V _{GS} = 10	OV (Figure 9)	-	0.021	0.025	Ω
THERMAL SPECIFICATIONS	1.				1		1
Thermal Resistance Junction to Case	$R_{ extsf{ heta}JC}$	(Figure 3)		-	-	0.74	°C/W
Thermal Resistance Junction to Ambient	R_{\thetaJA}	TO-247		-	-	30	°C/W
		TO-220, TO-263, TO-262		-	-	62	°C/W
SWITCHING SPECIFICATIONS ($V_{GS} = 10$	V)				1		I
Turn-On Time	ton	$V_{DD} = 50V, I_D \cong 56A,$ $R_L = 0.89\Omega, V_{GS} = 10V,$ $R_{GS} = 5.1\Omega$		-	-	110	ns
Turn-On Delay Time	t _{d(ON)}			-	15	-	ns
Rise Time	t _r			-	60	-	ns
Turn-Off Delay Time	t _{d(OFF)}			-	20	-	ns
Fall Time	t _f			-	25	ĸ	ns
Turn-Off Time	tOFF	_		-	-	70	ns
GATE CHARGE SPECIFICATIONS		-		I	4		
Total Gate Charge	Q _{g(TOT)}	$V_{GS} = 0V$ to 20V	$V_{DD} = 50V,$	-	110	130	nC
Gate Charge at 10V	Q _{g(10)}	$V_{GS} = 0V \text{ to } 10V$	to 2V $I_{g(REF)} = 1.0mA$	-	57	75	nC
Threshold Gate Charge	Q _{g(TH)}	$V_{GS} = 0V \text{ to } 2V$		-	3.7	4.5	nC
Gate to Source Gate Charge	Q _{gs}		(Figure 13)	-	9.8	-	nC
Gate to Drain "Miller" Charge	Q _{gd}	1		-	24	-	nC

Electrical Specifications $T_{C} = 25^{\circ}C$, Unless Otherwise Specified

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
CAPACITANCE SPECIFICATIONS						
Input Capacitance	C _{ISS}	$V_{DS} = 25V, V_{GS} = 0V,$	-	2000	-	pF
Output Capacitance	C _{OSS}	f = 1MHz (Figure 12)	-	500	-	pF
Reverse Transfer Capacitance	C _{RSS}		-	65	-	pF

Source to Drain Diode Specifications

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Source to Drain Diode Voltage	V _{SD}	I _{SD} = 56A	-	-	1.25	V
Reverse Recovery Time	t _{rr}	$I_{SD} = 56A$, $dI_{SD}/dt = 100A/\mu s$	-	-	110	ns
Reverse Recovered Charge	Q _{RR}	$I_{SD} = 56A$, $dI_{SD}/dt = 100A/\mu s$	-	-	320	nC

Typical Performance Curves

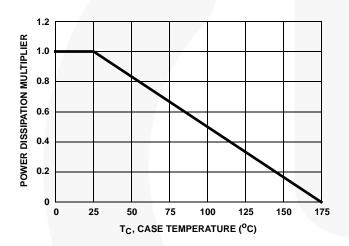


FIGURE 1. NORMALIZED POWER DISSIPATION vs CASE TEMPERATURE

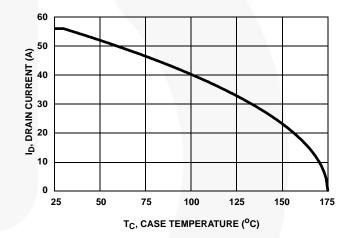


FIGURE 2. MAXIMUM CONTINUOUS DRAIN CURRENT vs CASE TEMPERATURE

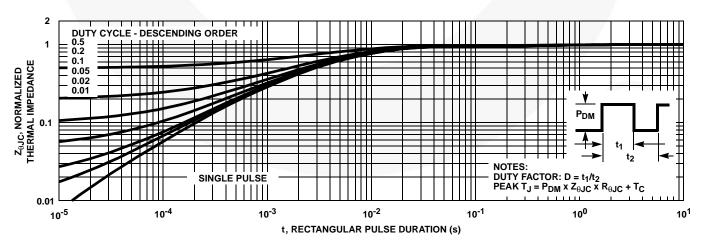
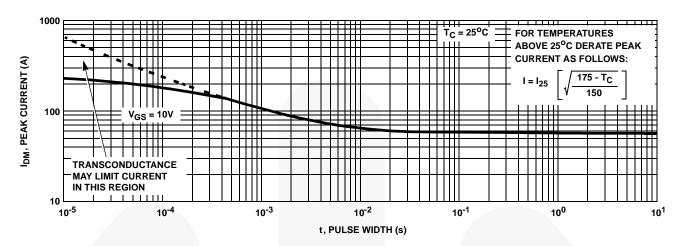
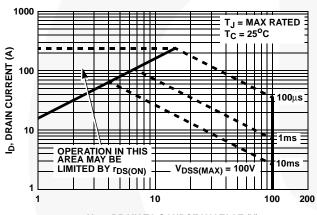


FIGURE 3. NORMALIZED MAXIMUM TRANSIENT THERMAL IMPEDANCE

Typical Performance Curves (Continued)







V_{DS}, DRAIN TO SOURCE VOLTAGE (V)

FIGURE 5. FORWARD BIAS SAFE OPERATING AREA

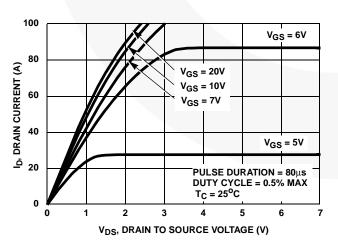
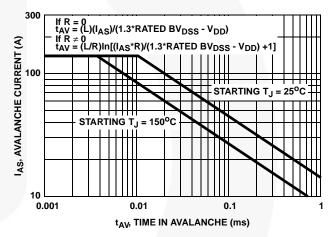


FIGURE 7. SATURATION CHARACTERISTICS



NOTE: Refer to Fairchild Application Notes AN9321 and AN9322. FIGURE 6. UNCLAMPED INDUCTIVE SWITCHING CAPABILITY

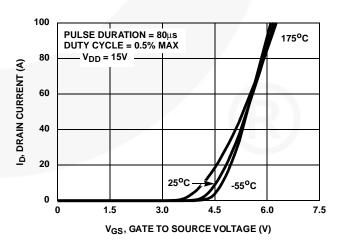
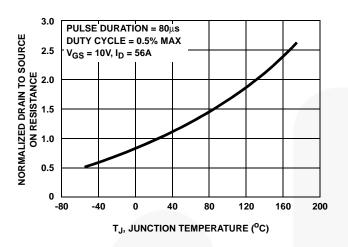
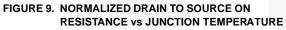


FIGURE 8. TRANSFER CHARACTERISTICS

Typical Performance Curves (Continued)





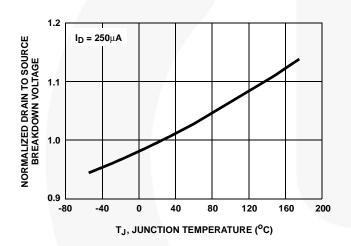


FIGURE 11. NORMALIZED DRAIN TO SOURCE BREAKDOWN VOLTAGE vs JUNCTION TEMPERATURE

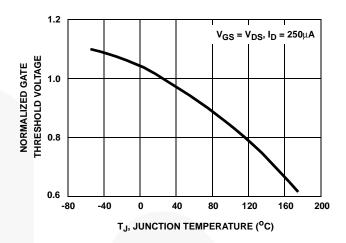
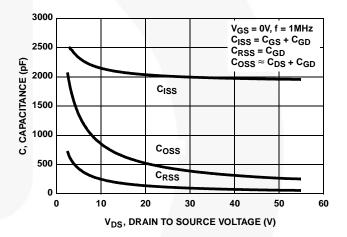
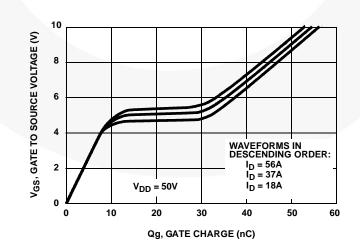


FIGURE 10. NORMALIZED GATE THRESHOLD VOLTAGE vs JUNCTION TEMPERATURE









Test Circuits and Waveforms

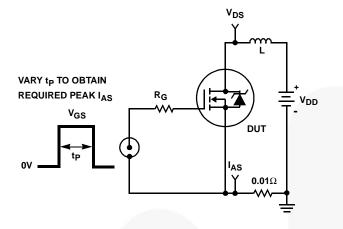


FIGURE 14. UNCLAMPED ENERGY TEST CIRCUIT

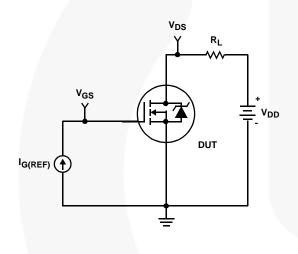


FIGURE 16. GATE CHARGE TEST CIRCUIT

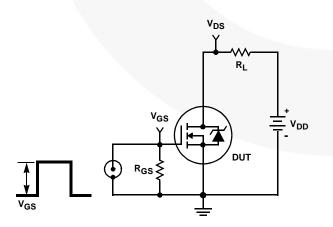


FIGURE 18. SWITCHING TIME TEST CIRCUIT

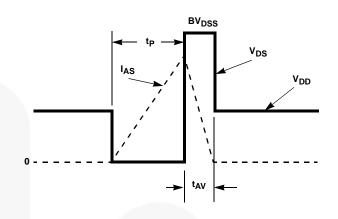
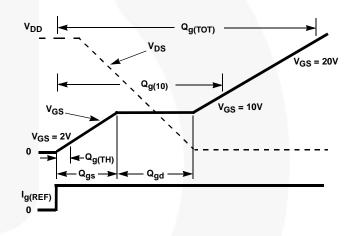


FIGURE 15. UNCLAMPED ENERGY WAVEFORMS





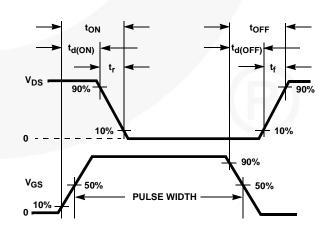
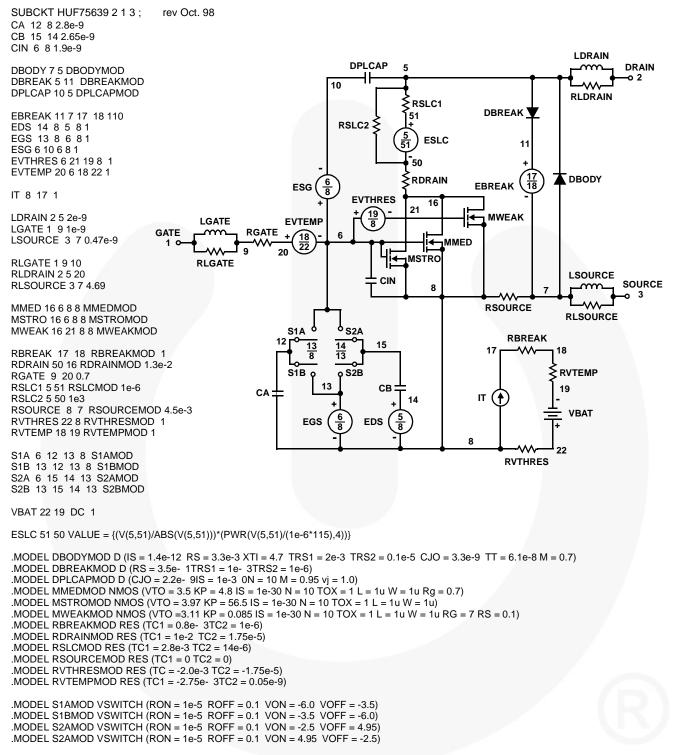


FIGURE 19. RESISTIVE SWITCHING WAVEFORMS

PSPICE Electrical Model



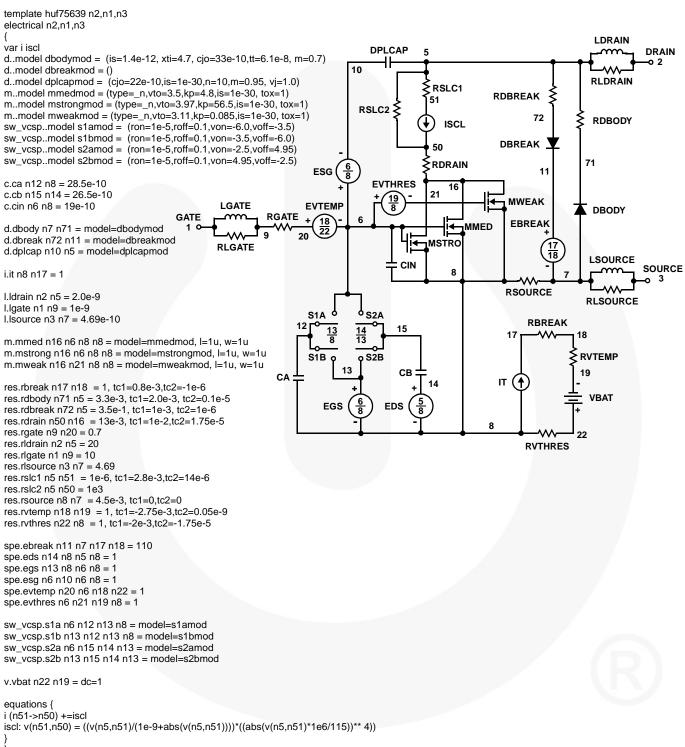
.ENDS

NOTE: For further discussion of the PSPICE model, consult A New PSPICE Sub-Circuit for the Power MOSFET Featuring Global Temperature Options; IEEE Power Electronics Specialist Conference Records, 1991, written by William J. Hepp and C. Frank Wheatley.

SABER Electrical Model

nom temp=25 deg c 100v Ultrafet

REV Oct. 98



Spice Thermal Model

REV APRIL 1998

HUF75639

CTHERM1 TH 6 2.8e-3 CTHERM2 6 5 4.6e-3 CTHERM3 5 4 5.5e-3 CTHERM4 4 3 9.2e-3 CTHERM5 3 2 1.7e-2 CTHERM6 2 TL 4.3e-2

RTHERM1 TH 6 5.0e-4 RTHERM2 6 5 1.5e-3 RTHERM3 5 4 2.0e-2 RTHERM4 4 3 9.0e-2 RTHERM5 3 2 1.9e-1 RTHERM6 2 TL 2.9e-1

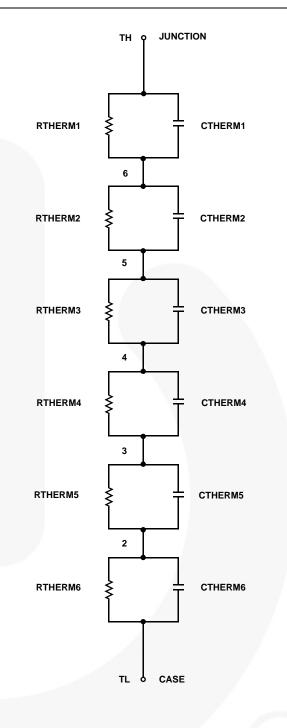
Saber Thermal Model

Saber thermal model HUF75639

template thermal_model th tl thermal_c th, tl

ctherm.ctherm1 th 6 = 2.8e-3ctherm.ctherm2 6 5 = 4.6e-3ctherm.ctherm3 5 4 = 5.5e-3ctherm.ctherm4 4 3 = 9.2e-3ctherm.ctherm5 3 2 = 1.7e-2ctherm.ctherm6 2 tl = 4.3e-2

rtherm.rtherm1 th 6 = 5.0e-4 rtherm.rtherm2 6 5 = 1.5e-3 rtherm.rtherm3 5 4 = 2.0e-2 rtherm.rtherm4 4 3 = 9.0e-2 rtherm.rtherm5 3 2 = 1.9e-1 rtherm.rtherm6 2 tl = 2.9e-1 }





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